R2J20701NP

## Peak Current Mode Synchronous Buck Controller with Power MOS FETs

REJ03G1459-0400
Rev. 4.00
Jun 30, 2008

## Description

This all-in-one SiP for POL (point-of-load) applications is a multi-chip module incorporating a high-side MOS FET, low-side MOS FET, and PWM controller in a single QFN package. The on and off timing of the power MOS FET is optimized by the built-in driver circuit, making this device suitable for large-current high-efficiency buck converters.
In a simple peak-current mode topology, stable operation is obtained in a closed power loop, and a fast converter is easily realized with the addition of simple components. Furthermore, the same topology can be applied to realize converters for parallel synchronized operation with current sharing, and two-phase operation.
The package also incorporates a high-side bootstrap Schottky barrier diode (SBD), eliminating the need for an external SBD for this purpose.

## Features

- Three chips in one package for high-efficiency and space saving
- Large average output current (35 A)
- Wide input voltage range: 8 to 14 V
- 0.6 V reference voltage accurate to within $1 \%$
- Wide programmable switching frequency: 200 kHz to 1 MHz
- Fast response by peak-current-mode topology.
- Simple current sharing (up to five modules in parallel)
- Two-phase operation in parallel operation
- Built-in SBD for boot strapping
- On/off control
- Hiccup operation under over load condition
- Tracking function
- Thin small package: 56 -pin QFN ( $8 \mathrm{~mm} \times 8 \mathrm{~mm}$ )
- Pb-free


## Applications

- Network equipment
- Telecommunications equipment
- Servers
- POL modules


## Typical Characteristic Curve



## Application Circuit Example



## Block Diagram



## Pin Arrangement



Note: All die-pads (three pads in total) should be soldered to PCB.

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## Pin Description

| Pin Name | Pin No. | Description | Remarks |
| :---: | :---: | :---: | :---: |
| VIN | 10 to 20 | Input voltage for the buck converter. |  |
| SW | 9, 21, 40 to 48 | Switching node. Connect a choke coil between the SW pin and dc output node of the converter. |  |
| PGND | 22 to 39 | Ground of the power stage. | Should be externally connected to SGND. |
| SGND | 6, 52 | Ground of the IC chip. | Should be externally connected to PGND. |
| VCIN | 7 | Input voltage for the control circuit. | Should be externally connected to VIN. |
| BOOT | 8 | Bootstrap voltage pin. A bootstrap capacitor should be connected between the BOOT and SW pin. | To be supplied +5 V through the internal SBD. |
| REG5 | 5 | +5 V logic power-supply output. | Requires decoupling from the GND plane by a capacitance $0.1 \mu \mathrm{~F}$. |
| ON/OFF | 50 | Signal disable pin. | Disabled when ON/OFF pin is in the low state. |
| IREF | 4 | Reference current generator for the IC. | Should be connected via $27 \mathrm{k} \Omega$ to the SGND pin. |
| CT | 55 | Timing capacitor pin for the oscillator. This pin has a select function for operation in slave mode. | If the pin voltage is $<1 \mathrm{~V}$ or $>4 \mathrm{~V}$, the IC operates in slave mode. |
| SYNC | 49 | I/O pin for synchronous operation. |  |
| TRK-SS | 56 | Start-up timing control input. |  |
| FB | 1 | Feedback voltage input for the closed loop. |  |
| EO | 3 | Error amplifier output pin. | Requires connection to an RC circuit for loop compensation. |
| Ishare | 2 | For current-sharing bus. | Simply connect the Ishare pins of all devices to get balanced current. |
| RAMP | 54 | RAMP signal input pin for peak current mode PWM control. |  |
| CS | 53 | Current output pin of active current sensing circuit. | Appropriate resistance is required between CS and the GND plane. |
| DRV5 | 51 | +5.25 V generator output for driving power MOS FETs. | Requires decoupling from the GND plane by a capacitance from $0.1 \mu \mathrm{~F}$ to $1.0 \mu \mathrm{~F}$. |

## Absolute Maximum Ratings

| $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$ |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| Item | Symbol | Rating | Unit | Note |
| Power dissipation | $\mathrm{Pt}(25)$ | 25 | W | 1 |
|  | $\mathrm{Pt}(100)$ | 8 |  | 1 |
| Average output current | lout | 35 | A |  |
| Input voltage | Vin (dc), Vcin (dc) | -0.3 to +16 | V | 2 |
|  | Vin (ac), Vcin (ac) | 20 |  | 2, 4 |
| Switch node voltage | Vsw (dc) | 16 | V | 2 |
|  | Vsw (ac) | 20 |  | 2, 4 |
| BOOT pin voltage | Vboot (dc) | 22 | V | 2 |
|  | Vboot (ac) | 25 |  | 2, 4 |
| ON/OFF pin voltage | Von/off | -0.3 to VIN | V | 2 |
| SYNC pin voltage | Vsync | -0.3 to +5.5 | V | 2 |
| Voltage on other pins | Vic | -0.3 to (REG5 + 0.3) | V | 2 |
| REG5 current | Ireg5 | -10 to 0 | mA | 3 |
| Ishare current | Ishare | -500 to 0 | $\mu \mathrm{A}$ | 3 |
| TRK-SS dc current | Itrk | 0 to 1 | mA | 3 |
| IREF current | Iref | -120 to 0 | $\mu \mathrm{A}$ | 3 |
| EO sink current | leo | 0 to 2 | mA | 3 |
| Operating junction temperature | Tj-opr | -40 to +150 | ${ }^{\circ} \mathrm{C}$ |  |
| Storage temperature | Tstg | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |  |

Notes: 1. Pt(25) represents a PCB temperature of $25^{\circ} \mathrm{C}$, and $\mathrm{Pt}(100)$ represents $100^{\circ} \mathrm{C}$.
2. Rated voltages are relative to voltages on the SGND and PGND pins.
3. For rated current, (+) indicates inflow to the chip and ( - ) indicates outflow.
4. Ratings for which "ac" is indicated are limited to within 100 ns .


## Electrical Characteristics

$\left(\mathrm{Ta}=25^{\circ} \mathrm{C}, \mathrm{VIN}=\mathrm{VCIN}=12 \mathrm{~V}\right.$, unless otherwise specified)

| Item |  | Symbol | Min | Typ | Max | Unit | Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply | VIN start threshold | VH | 6.8 | 7.2 | 7.6 | V |  |
|  | VIN shutdown threshold | VL | 6.45 | 6.85 | 7.25 | V |  |
|  | UVLO hysteresis | dUVL | - | $0.35 *^{1}$ | - | V |  |
|  | Input bias current | lin | 36 | 73 | 110 | mA | $\begin{aligned} & \text { CT }=68 \mathrm{pF}, \\ & \text { Duty cycle }=50 \% \\ & \hline \end{aligned}$ |
|  | Input shutdown current | Isd | 3.0 | 4.5 | 6.0 | mA | On/off = 0 V |
| 5-V regulator | Output voltage | Vreg | 4.8 | 5.0 | 5.2 | V |  |
|  | Line regulation | Vreg-line | -5 | 0 | +5 | mV | $\mathrm{VIN}=10$ to 16 V |
|  | Load regulation | Vreg-load | -8 | -3 | +2 | mV | Ireg $=0$ to 10 mA |
| $5.25-\mathrm{V}$ <br> regulator | Output voltage | Vdrv | 5.04 | 5.25 | 5.46 | V |  |
| Remote On/off | Disable threshold | Voff | 1.0 | 1.3 | 1.6 | V |  |
|  | Enable threshold | Von | 2.0 | 2.5 | 3.0 | V |  |
|  | Input current | Ion/off | 0.5 | 2.0 | 5.0 | $\mu \mathrm{A}$ | Von/off = 1 V |
| Reference current generator | IREF pin voltage | VIref | 2.6 | 2.7 | 2.8 | V | Riref $=27 \mathrm{k} \Omega$ |
| Oscillator | CT oscillating frequency | Fct | - | $930{ }^{* 1}$ | - | kHz | $\mathrm{CT}=68 \mathrm{pF}$ |
|  | SW switching frequency | Fsw | 418 | 465 | 512 | kHz | $\mathrm{CT}=68 \mathrm{pF}$ |
|  | CT higher trip voltage | Vhct | - | 3 *1 | - | V | $\mathrm{CT}=68 \mathrm{pF}$ |
|  | CT lower trip voltage | VIct | - | $2^{* 1}$ | - | V | $\mathrm{CT}=68 \mathrm{pF}$ |
|  | CT source current | Ict-src | -170 | -160 | -150 | $\mu \mathrm{A}$ | $\mathrm{CT}=1.5 \mathrm{~V}$ |
|  | CT sink current | Ict-snk | 150 | 160 | 170 | $\mu \mathrm{A}$ | $\mathrm{CT}=3.5 \mathrm{~V}$ |
|  | CT threshold for twophase operation | Vct-two | 3.6 | 4.0 | 4.4 | V |  |
|  | CT threshold for synchronous operation | Vct-one | 0.8 | 1.0 | 1.2 | V |  |
| SYNC and pulse generator | SYNC frequency | Fsync | 418 | 465 | 512 | kHz | $\mathrm{CT}=68 \mathrm{pF}$ |
|  | SYNC high voltage | Vh-sync | 4.0 | 5.0 | - | V | Rsync $=51 \mathrm{k} \Omega$ to GND |
|  | SYNC low voltage | VI-sync | 0 | - | 1.0 | V | Rsync $=51 \mathrm{k} \Omega$ to REG5 |
|  | SYNC input threshold | Vsync | 1.0 | 2.0 | 3.0 | V | $\mathrm{CT}=0 \mathrm{~V}$ or 5 V |
| Error amplifier | Feedback voltage | Vfb | 594 | 600 | 606 | mV | TRK-SS $=1 \mathrm{~V}$ |
|  | Input bias current | Ifb | -0.1 | 0 | +0.1 | $\mu \mathrm{A}$ | $\mathrm{FB}=0.6 \mathrm{~V}$ |
|  | Output source current | Io-src | 150 | 200 | 250 | $\mu \mathrm{A}$ | $\mathrm{EO}=4 \mathrm{~V}, \mathrm{FB}=0 \mathrm{~V}$ |
|  | Output sink transient current | Io-snk | 5.0 | 10.6 | 19.0 | mA | $\mathrm{EO}=1 \mathrm{~V}, \mathrm{FB}=1 \mathrm{~V}$ |
|  | Voltage gain | Av | - | $80^{* 1}$ | - | dB |  |
|  | Band width | BW | - | $15^{* 1}$ | - | MHz |  |
|  | Resistance connected to the Ishare pin | Rshare | 70 | 100 | 130 | k $\Omega$ | $\mathrm{EO}=0 \mathrm{~V}$. Ishare $=1 \mathrm{~V}$ |

Note: 1. These are reference values for design and have not been $100 \%$ tested in production.
$\left(\mathrm{Ta}=25^{\circ} \mathrm{C}, \mathrm{VIN}=\mathrm{VCIN}=12 \mathrm{~V}\right.$, unless otherwise specified)

| Item |  | Symbol | Min | Typ | Max | Unit | Test Conditions |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| Current <br> sense | CS current ratio | Idh/Ics | - | $18500^{* 1}$ | - | - |  |
|  | Leading edge blanking <br> time | TLD | - | $55^{* 1}$ | - | ns |  |
|  | CS comparator delay to <br> output | Td-cs | - | $50 *^{* 1}$ | - | ns |  |
|  | OCP comparator <br> threshold on CS pin | Vocp | 1.43 | 1.5 | 1.57 | V |  |
|  | Hiccup interval | Tocp | 1.98 | 2.20 | 2.42 | ms | $\mathrm{CT}=68 \mathrm{pF}$ |
|  | RAMP offset voltage | Vramp-dc | 77 | 92 | 107 | mV |  |
|  | CS offset current | Ics-dc | - | $490{ }^{* 1}$ | - | $\mu \mathrm{CS}=0 \mathrm{~V}$ |  |

Note: 1. These are reference values for design and have not been $100 \%$ tested in production.

## Description of Operation

## Peak Current Control

The control IC operates in a current-programmed control mode, in which the output of the converter is controlled by the choice of the peak current from the high-side MOS FET. The current from this MOS FET is sensed by an active current-sensing circuit (ACS), the output current of which is $1 / 18500$ ( 54 ppm ) of the MOS FET current. The ACS current is then converted to a certain voltage by the external resistor on the CS pin. The CS voltage is fed to the RAMP pin by an external connection, then compared with the current-control signal which is determined from the error amplifier output voltage (EO) via an NPN transistor and resistor network.

To start with, the RES pulse from the pulse generator resets a latch, then the high-side MOS FET is turned on. The latch output ( Q bar) is toggled when the voltage on RAMP reaches the level of the current-control signal on EO, the high-side MOS FET is turned off, and the low-side MOS FET is turned off after a certain dead-time interval. The IC remains in this state until the arrival of the next RES pulse.

Since current information is used in the control loop, loop compensation design for the converter is simple and easy.

## Maximum Duty-Cycle Limitation

If the current-sense comparator output is not toggled $50-\mathrm{ns}$ prior to the arrival of the next RES pulse, an internal maximum duty pulse is generated and forces toggling of the SR latch. So, the duty cycle of the high-side MOS FET is limited by the maximum duty period.

The maximum duty period of the high-side MOS FET depends on its switching frequency.

$$
\text { Maximum duty period }=1-50 \mathrm{~ns} \times \text { Fsw }
$$

## OCP Hiccup Operation

Once the voltage of CS exceeds 1.5 V , OCP hiccup circuit disables switching operation of the IC and MOS FETs.
Internal circuitry also pulls the TRK-SS pin down to SGND. The IC is turned off for a period of 1024 RES pulses; after this has elapsed, switching operation of the IC is restarted from the soft-start state.

## UVLO and On/off Control

When VIN (=Vcin) is below the start-up voltage, that is, is in the UVLO condition, functioning of the IC is disabled. The oscillator is turned off, both high- and low-side MOS FETs are turned off, and the TRK-SS pin is pulled down.

Furthermore, if the ON/OFF pin is in the low state or left open, functioning of the IC is disabled and both MOS FETs are turned off.

## Oscillator and Pulse Generator

The frequency of oscillation is set by the value of the external capacitor connected to the CT pin. This frequency is twice as high as the actual switching frequency. The frequencies are determined by the following equations:

$$
\begin{aligned}
& \text { Oscillator frequency; Fct }=160 \mu \mathrm{~A} /\{2 \times(\mathrm{CT}(\mathrm{~F})+18 \mathrm{pF}) \times 1 \mathrm{~V}\} \quad \text { (in } \mathrm{Hz}) \\
& \text { Switching frequency; Fsw }=0.5 \times \mathrm{Fct} \quad(\mathrm{~Hz})
\end{aligned}
$$

When the chip is operating in standalone mode or as the master chip for parallel operation, it requires a capacitor on the CT pin. In this case, the SYNC pin outputs a synchronization signal with a frequency of Fsw.

In operation as a slave chip, the CT pin must be connected to SGND or REG5, after which it acts as an input pin for the synchronized operation by external clock. The internal circuit is synchronized its rising edge when $\mathrm{CT}<0.8 \mathrm{~V}$, falling edge when $\mathrm{CT}>4.4 \mathrm{~V}$. In two-phase operation in parallel configuration, the CT pin should be at a voltage over 4.4 V .

| Item | Mode |  |  |  |
| :--- | :---: | :---: | :---: | :---: |
|  | Standalone | Master | Slave $-\mathbf{0}^{\circ}$ | Slave $-\mathbf{1 8 0}^{\circ}$ |
| CT pin | Has a cap. | Has a cap. | $<0.8 \mathrm{~V}$ | $>4.4 \mathrm{~V}$ |
| SYNC pin | Output mode | Output mode | Input mode | Input mode |
| Synchronizing trigger | - | - | Rising | Falling |

The internal RES pulse and maximum duty-cycle-control pulses are produced from the signal at half the oscillator frequency in standalone and master operating modes. In slave mode, internal pulses are produced from the externally supplied input signal on the SYNC pin.

## Current Sharing

It is easy to obtain balanced-current operation in a parallel configuration due to the application of peak current control.
To obtain current-sharing operation, simply tie the buffered error-amplifier outputs of all of the devices (Ishare pins) together.

No more than five devices can operate in parallel.

## Soft Start

Both simple soft starting and tracking start-up can be realized with the setup of the TRK-SS pin provided for soft-starts. The error amplifier has three inputs, two of which are designed to give priority to low-level non-inverting inputs for the amplifier. All that is required to realize soft-start operation is to simply attach an RC charging circuit to the TRK-SS pin.

The soft-start period is determined by the following equation, with C and R as the values for the RC charging circuit attached to the TRK-SS pin.
Tss = -C • R • Ln (1 - 0.6 V / REG5)

## Application Example

## Start-up Settings

Case 1) Standalone or master chip in parallel operation
With the RC network on the TRK-SS pin, the voltage on the pin should ramp up slowly.


Case 2) Coincident tracking
The TRS-SS signal for channel two is the voltage from Vout 1 after division by a resistor network. Vout 1 must be greater than Vout2. Cross-talk is not generated between the channels.


Case 3) Retiometric tracking
The TRS-SS of channel two is tied to TRK-SS of channel 1.
No cross talk is observed between the channels.


Case 4) Current sharing or two-phase operation
In the case of master-slave operation, the TRK-SS pin on the master device should be attached to an RC network for soft starts. TRK-SS pins of slave devices should be tied to the master's TRK-SS pin. The error amplifiers on the slave devices can be disabled by pulling up the corresponding FB pins to REG5, and the slave devices do not require loop-compensation networks.


## Choice of The Resistance of CS Pin

The CS pin is a current-output pin. A current $1 / 18500$ of that of the high-side MOS FET flows through this pin, which also has a dc current offset of $490 \mu \mathrm{~A}$. The converter's maximum current is determined by the voltage on the CS pin, i.e. 1.5 V , and by the value of the external resistor attached to this pin. The resistance is determined as shown below.

$$
\text { Specification: L = } 360 \mathrm{nH}, \mathrm{Vin}=12 \mathrm{~V} \text {, Vout }=1.8 \mathrm{~V}, \mathrm{Fsw}=500 \mathrm{kHz} \text {, lout }(\max )=25 \mathrm{~A}
$$

Current through the choke coil is

$$
\text { ILpp }=(\text { Vin }- \text { Vout }) \times \text { Vout } /(L \times \operatorname{Vin} \times F s w)=8.5 A(p-p)
$$

Peak choke current is the current when Io is at its maximum, i.e.

$$
\operatorname{IImax}=\mathrm{lo}(\max )+0.5 \times \mathrm{ILpp}=25 \mathrm{~A}+4.25 \mathrm{~A}=29.25 \mathrm{~A}
$$

Maximum CS pin output current is;

$$
\text { Icsmax }=\text { IImax } / 18500+\text { Ics-dc }=29.25 \mathrm{~A} / 18500+490 \mu \mathrm{~A}=2.071 \mathrm{~mA}
$$

The ideal resistance for attachment to the CS pin is

$$
\mathrm{RCS}=\mathrm{Vcl} / \text { Icsmax }=1.5 \mathrm{~V} / 2.071 \mathrm{~mA}=724 \Omega
$$

Therefore choose $750 \Omega$ as the value of the resistor for attachment to the CS pin.

## Output Voltage Setting

The error amplifier of the device has an accurate 0.6 V reference voltage. Feedback thus leads to a voltage of about 0.6 V on the FB pin once the converter system has stabilized, so the output voltage is

$$
\text { Vout }=0.6 \mathrm{~V} \times(\mathrm{R} 1+\mathrm{R} 2) / \mathrm{R} 2
$$



## Loop Compensation

Peak-current control makes design in terms of phase margins easier than is the case with voltage control. This is because of differences between the characteristics of the PWM modulator and power stage in the two methods.

Figures 1 and 2 show the behavior of the PWM modulator and power stage in the cases of voltage control and peak current control, respectively.


Feed-forward current to the modulator in the case of peak-current control means that the system is single pole, so we see a $-20 \mathrm{~dB} /$ decade cutoff and phase margin of $90^{\circ}$ in the Bode plot. In voltage control, the system configures a twopole pole system. That is why rather complicated loop compensation of the error amplifier is required, such as type-III compensation.
The design of effective compensation is thus much simpler in the case of peak-current control (refer to figure 3).


Figure 3 Error Amplifier Compensation

## Design example

Specification: $\mathrm{L}=360 \mathrm{nH}, \mathrm{Co}=600 \mu \mathrm{~F}, \mathrm{Fsw}=500 \mathrm{kHz}, \mathrm{Vin}=12 \mathrm{~V}$, Vout $=1.8 \mathrm{~V}, \mathrm{R} 1=2 \mathrm{k} \Omega, \mathrm{R} 2=1 \mathrm{k} \Omega$, RCS $=750 \Omega$

1. Flat-band gain of error amplifier

The flat-band gain is; $\mathrm{Af}=\mathrm{Rf} /(\mathrm{R} 1 / / \mathrm{R} 2) / 2 \times\{\mathrm{R} 2 /(\mathrm{R} 1+\mathrm{R} 2)\}$
Hence, $R f=2 \times A f \times R 1 \ldots \ldots(1)$

In the Bode plot, the total gain should be less than $1(0 \mathrm{~dB})$ at the switching frequency.
The total gain at Fsw (= Asw) depends on the flat-band gain, so Af should be expressed as follows.

$$
\begin{align*}
& \text { Af }=\text { Asw } \times 2 \pi \times \mathrm{Fsw} \times \mathrm{Co} \times \mathrm{RCS} / \mathrm{Nt} \ldots \ldots(  \tag{2}\\
& \text { Here }, \mathrm{Nt}=\mathrm{Idh} / \mathrm{Ics}=18500
\end{align*}
$$

In the typical way, the value chosen for Asw is in the range from 0.1 to 0.5 , since this produces a stable control loop.
The transient response will be faster if a larger Asw is adopted ,but the system might be unstable.
We choose 0.2 for Asw in the example below.

$$
\begin{aligned}
& \mathrm{Af}=0.2 \times 2 \pi \times 500 \mathrm{kHz} \times 600 \mu \mathrm{~F} \times 750 \Omega / 18500=15.283 \\
& \mathrm{Rf}=2 \times 15.283 \times 2 \mathrm{k} \Omega=61.132 \mathrm{k} \Omega
\end{aligned}
$$

Therefore, we select a value of $62 \mathrm{k} \Omega$ for Rf.
2. Selecting the Cf value to determine the frequency of the zero

The frequency of the zero established by Cf and Rf is about ten times the frequency of the pole for the power stage and modulator.
We must start with the dc gain of the power stage and modulator.

$$
\begin{equation*}
\mathrm{A} 0=\frac{2 \times \mathrm{Nt} / \mathrm{RCS} \times \mathrm{L} \times \mathrm{Vin} \times \mathrm{Fsw}}{\mathrm{SQRT}\left\{\mathrm{Vin}^{2}-8 \times \mathrm{L} \times \operatorname{Vin} \times \mathrm{Fsw} \times(\mathrm{VCSO} \times \mathrm{Nt} / \mathrm{RCS})\right\}} \tag{3}
\end{equation*}
$$

Here VCS0 is the peak ac voltage on the CS pin when the load current is zero, thus

$$
\begin{aligned}
\text { VCSO } & =0.5 \times \mathrm{RCS} \times(\text { Vin }- \text { Vout }) \times \text { Vout } /(\mathrm{L} \times \mathrm{Vin} \times \mathrm{Fsw}) / 18500 \ldots \ldots . .(4) \\
& =0.5 \times 750 \Omega \times(12 \mathrm{~V}-1.8 \mathrm{~V}) \times 1.8 \mathrm{~V} /(360 \mathrm{nH} \times 12 \mathrm{~V} \times 500 \mathrm{kHz}) / 18500 \\
& =0.172 \mathrm{~V}
\end{aligned}
$$

Equation (3)

$$
\begin{align*}
\mathrm{A} 0 & =\frac{2 \times \mathrm{Nt} / \mathrm{RCS} \times \mathrm{L} \times \mathrm{Vin} \times \mathrm{Fsw}}{\mathrm{SQRT}\left\{\mathrm{Vin}^{2}-8 \times \mathrm{L} \times \mathrm{Vin} \times \mathrm{Fsw} \times(\mathrm{VCSO} \times \mathrm{Nt} / \mathrm{RCS})\right\}} \cdots \ldots .(3)  \tag{3}\\
& =\frac{2 \times 18500 / 750 \Omega \times 360 \mathrm{nH} \times 12 \mathrm{~V} \times 500 \mathrm{kHz}}{\operatorname{SQRT}\left\{12 \mathrm{~V}^{2}-8 \times 360 \mathrm{nH} \times 12 \mathrm{~V} \times 500 \mathrm{kHz} \times(0.172 \mathrm{~V} \times 18500 / 750 \Omega)\right\}} \\
& =\frac{106.56}{\operatorname{SQRT}\{70.687\}} \\
& =12.674
\end{align*}
$$

The frequency of the pole established by the power stage and modulator is

$$
\begin{equation*}
\mathrm{FO}=\mathrm{Nt} /(2 \pi \times \mathrm{Co} \times \mathrm{RCS} \times \mathrm{A} 0) \tag{5}
\end{equation*}
$$

$\qquad$

Thus,

$$
\text { F0 }=18500 /(2 \pi \times 600 \mu \mathrm{~F} \times 750 \Omega \times 12.674)=516 \mathrm{~Hz}
$$

Therefore, the frequency of the zero established by Cf and Rf is
Fzero $=10 \times \mathrm{FO}=5.16 \mathrm{kHz}$
$\mathrm{Cf}=(2 \pi \times \text { Fzero } \times \mathrm{Rf})^{-1}=(2 \pi \times 5.16 \mathrm{kHz} \times 62 \mathrm{k} \Omega)^{-1}=497 \mathrm{pF}$
Therefore, we select the value 510 pF for Cf .
Basically, the transient response is faster when Cf is smaller, but too small a value will make the system-loop unstable.


Figure 4

## Study of Vout Accuracy

The nominal output voltage is calculated as

$$
\begin{equation*}
\text { Vout }=V F B \times(R 1+R 2) / R 2 \tag{6}
\end{equation*}
$$

Here, the typical feedback voltage is 0.6 V .


The accuracy of Vout is strongly dependent on the variation of VFB, R1 and R2. VFB has a variation of $1 \%$ and resistance intrinsically has a certain variation. When we take the variation in resistance into account, equation (6) is extended to produce equation (7).

$$
\begin{align*}
\text { Vout } & =\frac{R 1 \times K 1+R 2 \times K 2}{R 2 \times K 2} \times V F B \\
& =\frac{R 1 \times K 1 / K 2+R 2}{R 2} \times V F B \tag{7}
\end{align*}
$$

Here, K1 and K2 are coefficients. Both are 1.00 in the ideal case.

By equation (6), R1 is chosen as

$$
\begin{equation*}
\mathrm{R} 1=\left[\frac{\text { Vout (typical) }}{\text { VFB (typical) }}-1\right] \times \mathrm{R} 2 \tag{8}
\end{equation*}
$$

Substituting this expression for R1 into equation (7) yields the following.

$$
\begin{equation*}
\text { Vout }=\text { VFB } \times\left\{\left[\frac{\text { Vout (typical) }}{\text { VFB (typical) }}-1\right] \times \frac{\mathrm{K} 1}{\mathrm{~K} 2}+1\right\} \tag{9}
\end{equation*}
$$

Therefore, variation in Vout is expressed as

$$
\begin{equation*}
\frac{\text { Vout }}{\text { Vout (typical) }}=\left[\frac{\text { VFB }}{\text { Vout (typical) }} \times\left\{\left[\frac{\text { Vout (typical) }}{\text { VFB (typical) }}-1\right] \times \frac{\mathrm{K} 1}{\mathrm{~K} 2}+1\right\}-1\right] \times 100(\%) \tag{10}
\end{equation*}
$$

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The accuracy of Vout can be estimated by using equation (10).
For example, if Vout (typical) $=1.8 \mathrm{~V}$, resistance variation is $1 \%$ (i.e. $\mathrm{K} 1, \mathrm{~K} 2=1.01$ and 0.99 ), and $\mathrm{VFB}=594 \mathrm{mV}$ to 606 mV :

$$
\begin{aligned}
\frac{\text { Vout }}{\text { Vout (typical) }} & =\left[\frac{\mathrm{VFB}}{\text { Vout (typical) }} \times\left\{\left[\frac{\text { Vout (typical) }}{\mathrm{VFB}(\text { typical) }}-1\right] \times \frac{\mathrm{K} 1}{\mathrm{~K} 2}+1\right\}-1\right] \times 100(\%) \\
& =\left[\frac{606 \mathrm{mV}}{1.8 \mathrm{~V}} \times\left\{\left[\frac{1.8 \mathrm{~V}}{600 \mathrm{mV}}-1\right] \times \frac{1.01}{0.99}+1\right\}-1\right] \times 100(\%) \\
& =2.36 \% \\
& =\left[\frac{594 \mathrm{mV}}{1.8 \mathrm{~V}} \times\left\{\left[\frac{1.8 \mathrm{~V}}{600 \mathrm{mV}}-1\right] \times \frac{0.99}{1.01}+1\right\}-1\right] \times 100(\%) \\
& =-2.31 \%
\end{aligned}
$$

Therefore, the output accuracy will be $\pm 2.3 \%$ under the above conditions.
Figure 5 shows the relationship between the accuracy of the resistance and the accuracy of the output voltage. The resistor value must have an accuracy of $0.5 \%$ if the variation in output voltage from the system is to be kept within two percent across the voltage range from 0.6 to 3.3 V .


Figure 5 Vout Accuracy vs. Vout Set Voltage

## Current Sharing



## External Synchronization



Current Sharing and Synchronization


## Two-Phase Operation



## Timing Chart

## Peak Current Control



Note: Propagation delay is ignored

## Oscillator and Pulse Generator

1. Standalone operation or operation as the master chip in a parallel configuration with other chips.


Note: Propagation delay is ignored.

Frequency of oscillation for CT:

$$
\begin{equation*}
\text { Fct }=\frac{160 \mu \mathrm{~A}}{2 \times(\mathrm{CT}(\mathrm{~F})+18 \mathrm{pF}) \times 1 \mathrm{~V}} \tag{Hz}
\end{equation*}
$$

Switching frequency

$$
\text { Fsw }=0.5 \times \text { Fct } \quad(H z)
$$

Frequency setting range (for Fsw): 200 kHz to 1 MHz (i.e. 400 kHz to 2 MHz for Fct)

## R2J20701NP

2. Operation as a slave chip (simple synchronous operation)


Note: Propagation delay is ignored.
3. Operation as a slave chip in a parallel configuration (two-phase operation)


Note: Propagation delay is ignored.

Hiccup Operation when the Over-Current Limit (OCL) is Reached


Note: Propagation delay is ignored.

## Main Characteristics




## Package Dimensions



RenesasTechnology Corp. Sales Straetegic Planning Div. Nippon Bldg., 2---2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
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## Renesas Technology America, Inc.

450 Holger Way, San Jose, CA $95134-1368$, U.S.A
Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

## Renesas Technology Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900
Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No. 1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120
Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

## Renesas Technology Hong Kong Ltd

7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: <852>2265-6688, Fax: <852> 2377-3473

## Renesas Technology Taiwan Co., Ltd

10th Floor, No.99, Fushing North Road, Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399
Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, \#06-10, Keppel Bay Tower, Singapore 098632
Tel: <65> 6213-0200, Fax: <65> 6278-8001

## Renesas Technology Korea Co., Ltd.

Kukje Center Bldg. 18th FI., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea
Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145
Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

